High Voltage Switching Diode
Lead free product
Halogen-free type

FETURE

- We declare that the material of product compliance with RoHS requirements.

BAS21GH

SOT-23 (TO-236AB)

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Continuous Reverse Voltage	V_R	250	Vdc
Peak Forward Current	I_F	200	mAdc
Peak Forward Surge Current	$I_{FM(surge)}$	625	mAdc

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR– 5 Board, (1) T_A = 25°C Derate above 25°C	P_D	225 1.8	mW mW/°C
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	556	°C/W
Total Device Dissipation Alumina Substrate, (2) T_A = 25°C Derate above 25°C	P_D	300 2.4	mW mW/°C
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	417	°C/W
Junction and Storage Temperature	T_J , T_{stg}	–55 to +150	°C

ELECTRICAL CHARACTERISTICS (T A = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS				
Reverse Voltage Leakage Current	I_R			µAdc
(V_R = 200Vdc)		—	0.1	
(V_R = 200Vdc, T_J = 150°C)		—	100	
Reverse Breakdown Voltage (I_{BR} = 100 µAdc)	$V_{(BR)}$	250	—	Vdc
Forward Voltage	V_F			mV
(I_F = 100 mAdc)		—	1000	
(I_F = 200 mAdc)		—	1250	
Diode Capacitance (V_R = 0, f = 1.0 MHz)	C_D	—	5.0	pF
Reverse Recovery Time (I_F = I_R = 30mAdc, R_L = 100 Ω)	t_{rr}	—	50	ns

1. FR–5 = 1.0 x 0.75 x 0.062 in.
2. Alumina = 0.4 x 0.3 x 0.024 in. 99.5% alumina.

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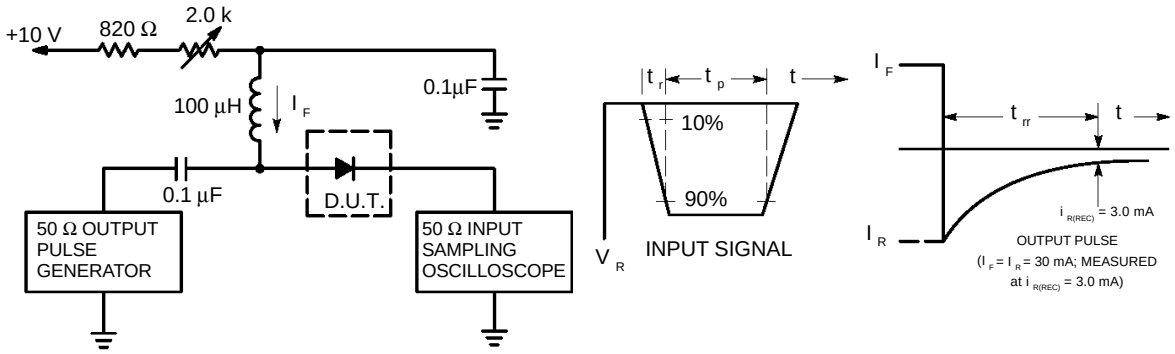
Figure 1. Recovery Time Equivalent Test Circuit



Notes: 1. A 2.0 kΩ variable resistor adjusted for a Forward Current (I_F) of 30 mA.

2. Input pulse is adjusted so $I_{R(peak)}$ is equal to 30 mA.

3. $t_p >> t_{rr}$

DEVICE MARKING AND ORDERING INFORMATION

Device	Marking	Reel	Reel (pcs)	Carton (pcs)	Packaging
BAS21GH	**JS**	7"	3,000	60,000 120,000	SOT-23

PACKAGE DIMENSIONS

SOT-23

Unit : mm